## ペロブスカイト及び関連酸化物の電子状態計算(7)

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## **Electronic State Calculations of Perovskite and Perovskite-related Oxides (7)**

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We have studied the ferroelectricity disappearance phenomenon in BaTiO<sub>3</sub> thin films using the Discrete Variational-X  $\alpha$  molecular-orbital method. This study have configured calculation model of BaTiO<sub>3</sub> with electrodes. We have calculated electronic states of the BaYiO<sub>3</sub> by using the model, and evaluated the change of Ti 3d-O 2p overlap population against film thickness. As a calculated result, we have found that the changes of external field and film thickness influence the magnitudes of spontaneous polarization field, and then they influence presence ferroelectricity of a BaTiO<sub>3</sub>.